# LITEON SEMICONDUCTORS

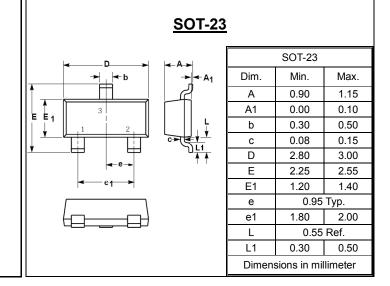
### SURFACE MOUNT FAST SWITCHING DIODE

#### FEATURES

- Fast switching speed
- · Ideally suited for automatic insertion
- For general purpose switching applications

#### **MECHANICAL DATA**

- Case: SOT-23 Plastic
- Case material: "Green" molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl)
- Moisture sensitivity: Level 1 per J-STD-020D
- Lead free in RoHS 2002/95/EC compliant



### **Maximum Ratings & Thermal Characteristics** @ T<sub>A</sub> = 25°C unless otherwise specified

	-		
Characteristic	Symbol	BAS116	Units
Repetitive Peak Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	75	V
Forward Continuous Current	I <sub>FM</sub>	200	mA
Non-Repetitive Peak Forward @t=1.0us	I <sub>FSM</sub>	2	А
Power Dissipation	PD	225	mW
Operating Temperature Range	TJ	150	°C
Storage Temperature Range	T <sub>STG</sub>	-55~+150	°C

## **Electrical Characteristics** @ $T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Test Condition	Symbol	Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage	I <sub>R</sub> = 100uA	V <sub>BR</sub>	75			V
Maximum Forward Voltage	$I_{F} = 1mA$ $I_{F} = 10mA$ $I_{F} = 50mA$ $I_{F} = 150mA$	V <sub>F</sub>	  	   	0.9 1.0 1.1 1.25	V
Maximum DC Reverse Current at Rated DC Blocking Voltage	V <sub>R</sub> = 75V	I <sub>R</sub>			5	nA
Typical Diode Capacitance	V <sub>R</sub> =0V,f=1MHz	CD		2		pF
Reverse Recovery time	Irr=1mA, I <sub>R</sub> =I <sub>F</sub> =10mA R <sub>L</sub> =100Ω	trr			6	ns
				DEV	3 Oct-2010	

REV.3, Oct-2010, KSYR17

## REVERSE VOLTAGE – 75 Volts FORWARD CURRENT – 0.2 Ampere

## **BAS116**

## RATING AND CHARACTERISTIC CURVES BAS116

#### Fig.1 Current Derating Curve **Fig.2 Typical Forward Characteristics** 300 300 (1) T<sub>j</sub> = 150 °C; typical values. Device mounted on an FR4 printed-circuit board (2) T<sub>j</sub> = 25 °C; typical values. ۱<sub>F</sub> (3) T<sub>j</sub> = 25 °C; maximum values. 250 (mA) IF, FORWARD CURRENT (mA) 200 200 (1) (2) (3) 150 100 100 50 0 0 50 100 150 200 0 1.2 <sub>V F</sub> (V) 1.6 0 0.4 0.8 TA, AMBIENT TEMPERATURE (°C) Fig.3 Maximum permissible non-repetitive peak forward current 10<sup>2</sup> Based on square wave currents; T<sub>j</sub> = 25 °C prior to surge I<sub>FSM</sub> (A) 10 +1 +Ш 10-1 1 10 10<sup>2</sup> 10<sup>3</sup> 10<sup>4</sup> t<sub>p</sub> (μs) Fig.4 Typical Reverse Characteristics Fig.5 Total Capacitance vs. Reverse Voltage 2 10<sup>2</sup> $I_R$ (nA) 10 **≡**(1) Cd (pF) 1 1 10<sup>-1</sup> (2) 10<sup>-2</sup> 10<sup>-3</sup> 0 т<sub>ј</sub> (°С)<sup>200</sup> 0 50 100 150 $^{15}$ V<sub>R</sub>(V) $^{20}$ 0 5 10

## Device Marking :

Device P/N	Marking code	Equivalent Circuit Diagram
BAS116	JV	3 <b>oo</b> 1



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